

# iscN-Channel MOSFET Transistor

2SK3700

## • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(ON) = 2.5Ω (MAX)
- Enhancement mode:Vth = 2 to 4 V (VDS = 10 V, ID=1.0mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

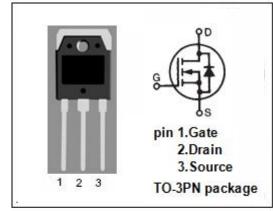
· Switching Voltage Regulators

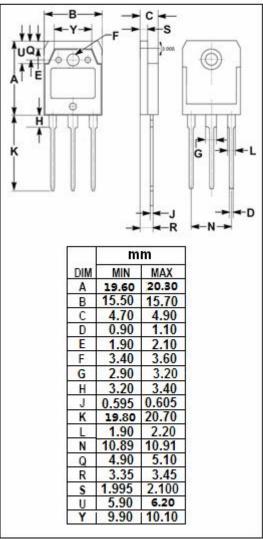
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	900	<b>V</b>
$V_{GS}$	Gate-Source Voltage	irce Voltage ±30	
l <sub>D</sub>	Drain Current-Continuous 5		Α
I <sub>DM</sub>	Drain Current-Single Pulsed	15	Α
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	150	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.833	°C/W





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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	900			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =3A			2.5	Ω
Igss	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±10	μ Α
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =720V; V <sub>GS</sub> = 0V			100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =5A, V <sub>GS</sub> = 0 V			1.7	V



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